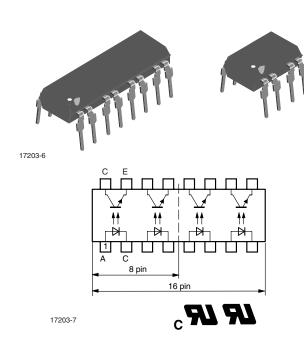


Vishay Semiconductors

Optocoupler, Phototransistor Output



FEATURES

- DC isolation test voltage 5000 V_{RMS}
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Pb-free



APPLICATIONS

- Programmable logic controllers
- Modems
- Answering machines
- · General applications

AGENCY APPROVALS

- UL1577, file no. E57244 system code H, double protection
- cUL tested to CSA 22.2 bulletin 5A, UL1577, file no. E52744

DESCRIPTION

In the K827PH, K847PH parts each channel consist of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 8 pin (dual); 16 pin (quad) plastic dual inline package.

ORDER INFORMATION	
PART	REMARKS
K827PH	CTR 50 % to 600 %, DIP-8
K847PH	CTR 50 % to 600 %, DIP-16

Note

K827PH and K847PH are marked as K827P and K847P respectively.

ABSOLUTE MAXIMUM RATINGS (1) (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
INPUT						
Reverse voltage		V_{R}	6	V		
Forward current		I _F	60	mA		
Forward surge current	t _P ≤ 10 μs	I _{FSM}	1.5	А		
Power dissipation		P _{diss}	100	mW		
Junction temperature		Tj	125	°C		
OUTPUT						
Collector emitter voltage		V _{CEO}	70	V		
Emitter collector voltage		V _{ECO}	7	V		
Collector current		Ic	50	mA		
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA		
Power dissipation		P _{diss}	150	mW		
Junction temperature		Tj	125	°C		

K827PH, K847PH

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ABSOLUTE MAXIMUM RATINGS ⁽¹⁾ (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
COUPLER								
AC isolation test voltage (RMS)	t = 1 min	V _{ISO}	5000	V_{RMS}				
Total power dissipation		P _{tot}	250	mW				
Operating ambient temperature range		T _{amb}	- 40 to + 100	°C				
Storage temperature range		T _{stg}	- 55 to + 125	°C				
Soldering temperature (2)	2 mm from case, $t \le 10 \text{ s}$	T _{sld}	260	°C				

Notes

⁽²⁾ Refer to wave profile for soldering conditions for through hole devices.

ELECTRICAL CHARACTERISTICS (1) (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT								
Forward voltage	I _F = 50 mA	V_{F}		1.25	1.6	V		
Junction capacitance	$V_R = 0 V, f = 1 MHz$	C _j		50		pF		
OUTPUT	OUTPUT							
Collector emitter voltage	I _C = 100 μA	V_{CEO}	70			V		
Emitter collector voltage	I _E = 100 μA	V _{ECO}	7			V		
Collector dark current	$V_{CE} = 20 \text{ V}, I_F = 0, E = 0$	I _{CEO}			100	nA		
COUPLER								
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$	V _{CEsat}			0.3	V		
Cut-off frequency	$I_F = 10 \text{ mA}, V_{CE} = 5 \text{ V},$ $R_L = 100 \ \Omega$	f _c		100		kHz		
Coupling capacitance	f = 1 MHz	C _k		0.3		pF		

Note

⁽¹⁾ Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I _C /I _F	$V_{CE} = 5 \text{ V}, I_F = 5 \text{ mA}$	K827PH	CTR	50		600	%
		K847PH	CTR	50		600	%

⁽¹⁾ Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.



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SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Delay time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t _d		3		μs
Rise time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t _r		3		μs
Fall time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t _f		4.7		μs
Storage time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t _s		0.3		μs
Turn-on time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t _{on}		6		μs
Turn-off time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t _{off}		5		μs
Turn-on time	V_S = 5 V, I_F = 10 mA, R_L = 1 k Ω (see figure 2)	t _{on}		9		μs
Turn-off time	V_S = 5 V, I_F = 10 mA, R_L = 1 k Ω (see figure 2)	t _{off}		18		μs

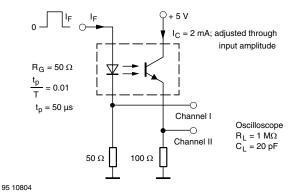


Fig. 1 - Test Circuit, Non-Saturated Operation

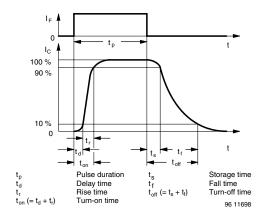


Fig. 3 - Switching Times

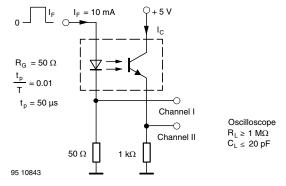


Fig. 2 - Test Circuit, Saturated Operation

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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

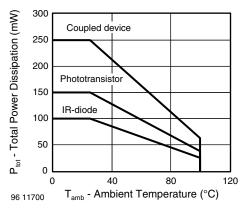
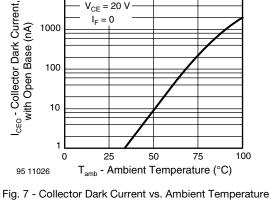


Fig. 4 - Total Power Dissipation vs. Ambient Temperature



V_{CE} = 20 V

10 000

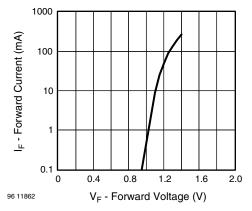


Fig. 5 - Forward Current vs. Forward Voltage

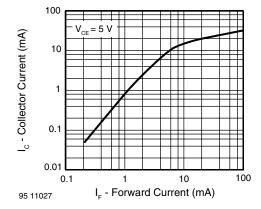


Fig. 8 - Collector Current vs. Forward Current

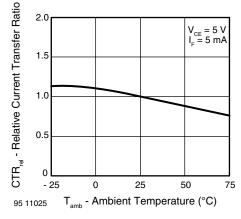


Fig. 6 - Relative Current Transfer Ratio vs. Ambient Temperature

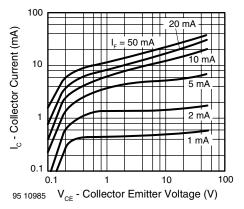


Fig. 9 - Collector Current vs. Collector Emitter Voltage



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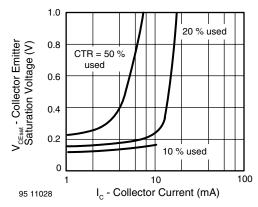


Fig. 10 - Collector Emitter Saturation Voltage vs. Collector Current

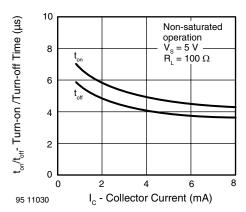


Fig. 13 - Turn-on/off Time vs. Collector Current

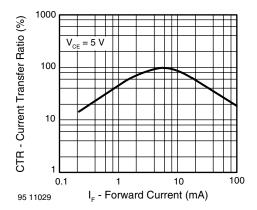


Fig. 11 - Current Transfer Ratio vs. Forward Current

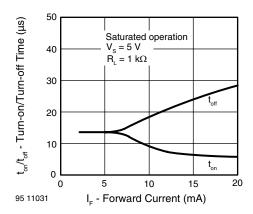
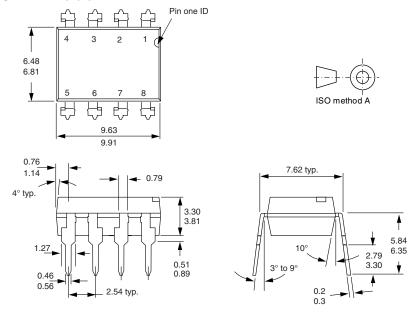


Fig. 12 - Turn-on/Turn-off Time vs. Forward Current

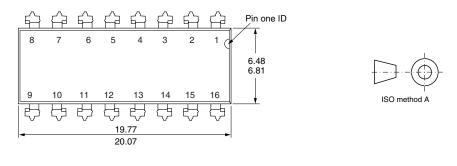
Vishay Semiconductors Optocoupler, Phototransistor Output

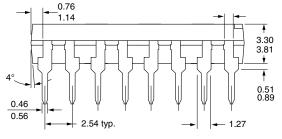


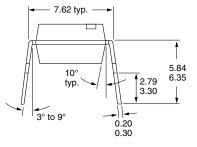
PACKAGE DIMENSIONS in millimeters



i178006

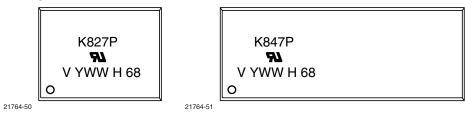






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PACKAGE MARKING





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Vishay

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